

**KS54AHCT 182**  
**KS74AHCT**

**Look Ahead Carry Generator**

**FEATURES**

- Compatible Carry Functions for direct ALU connection
- Cascadable to perform look-ahead across n-bit adders.
- High output current drive:  $I_{OL} = 8mA @ V_{OL} = 0.5V$
- Low power consumption characteristic of CMOS
- Direct interface capability to TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:

KS74AHCT: -40°C to +85°C  
KS54AHCT: -55°C to +125°C

- Package options include plastic "small outline" packages, standard plastic and ceramic 300-mil DIPs

**DESCRIPTION**

The '182 is a high-speed, look-ahead carry generator, capable of anticipating a carry across four binary adders or group of adders. These devices can be cascaded to perform full look-ahead across n-bit adders. Carry, generate-carry, and propagate-carry functions are provided as shown in the pin designation table.

When used in conjunction with the AHCT181 arithmetic logic unit, these generators provide high-speed carry look-ahead capability for any word length. Each 182 generates the look-ahead (anticipated carry) across a group of four ALUs and, in addition, other carry look-ahead circuits may be employed to anticipate carry across sections of four look-ahead packages up to n-bits. The method of cascading circuits to perform multi-level look-ahead is illustrated under typical application data.

Carry input and output of the ALU's are in their true form, and the carry propagate (P) and carry generate (G) are in negated form; therefore, the carry functions (inputs, outputs, generate, and propagate) of the look-ahead generators are implemented in the compatible forms for direct connection to the ALU. Reinterpretations of carry functions, as explained on the 181 data sheet are also applicable to and compatible with the look-ahead generator. Logic equations for the 182 are:

$$C_{n+x} = G_0 + P_0 C_n$$

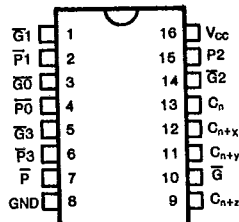
$$C_{n+y} = G_1 + P_1 G_0 + P_1 P_0 C_n$$

$$C_{n+z} = G_2 + P_2 G_1 + P_2 P_1 G_0 + P_2 P_1 P_0 C_n$$

$$\bar{G} = \bar{G}_3 + P_3 \bar{G}_2 + P_3 P_2 \bar{G}_1 + P_3 P_2 P_1 \bar{G}_0$$

$$P = P_3 P_2 P_1 P_0$$

**PIN CONFIGURATION**



**PIN DESIGNATIONS**

Designation	Pin No	Function
$\bar{G}_0, \bar{G}_1, \bar{G}_2, \bar{G}_3$	3, 1, 14, 5	Active Low Carry Generate Inputs
$\bar{P}_0, \bar{P}_1, \bar{P}_2, \bar{P}_3$	4, 2, 15, 6	Active Low Carry Propagate Inputs
$C_n$	13	Carry Input, Active HIGH
$C_{n+x}, C_{n+y}, C_{n+z}$	12, 11, 9	Carry Outputs
$\bar{G}$	10	Active Low Carry Generate Output
$P$	7	Active Low Carry Propagate Output
$V_{CC}$	16	Supply Voltage
$GND$	8	Ground

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**FUNCTION TABLES**

FOR  $\bar{G}$  OUTPUT

INPUTS							OUTPUT
$\bar{G}_3$	$\bar{G}_2$	$\bar{G}_1$	$\bar{G}_0$	$\bar{P}_3$	$\bar{P}_2$	$\bar{P}_1$	$\bar{G}$
L	X	X	X	X	X	X	L
X	L	X	X	L	X	X	L
X	X	L	X	L	L	X	L
X	X	X	L	L	L	L	L
All other combinations							H

FOR  $\bar{P}$  OUTPUT

INPUTS				OUTPUT
$\bar{P}_3$	$\bar{P}_2$	$\bar{P}_1$	$\bar{P}_0$	$\bar{P}$
L	L	L	L	L
All other combinations				H

FOR  $C_{n+x}$  OUTPUT

INPUTS				OUTPUT
$\bar{G}_0$	$\bar{P}_0$	$C_n$	$C_{n+x}$	
L	X	X		H
X	L	H		H
All other combinations				L

$C_{n+y}$  OUTPUT

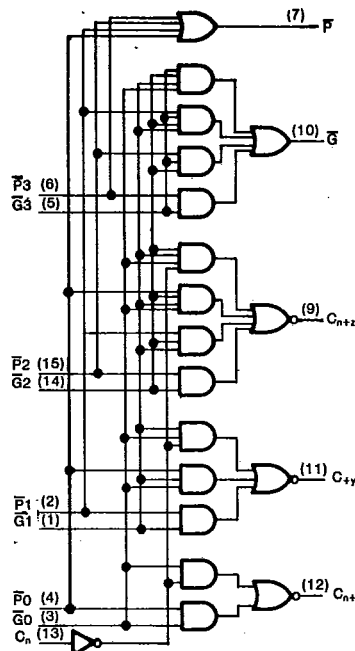
INPUTS					OUTPUT
$\bar{G}_1$	$\bar{G}_0$	$\bar{P}_1$	$\bar{P}_0$	$C_n$	$C_{n+y}$
L	X	X	X	X	H
X	L	L	X	X	H
X	X	L	L	H	H
All other combinations					L

$C_{n+z}$  OUTPUT

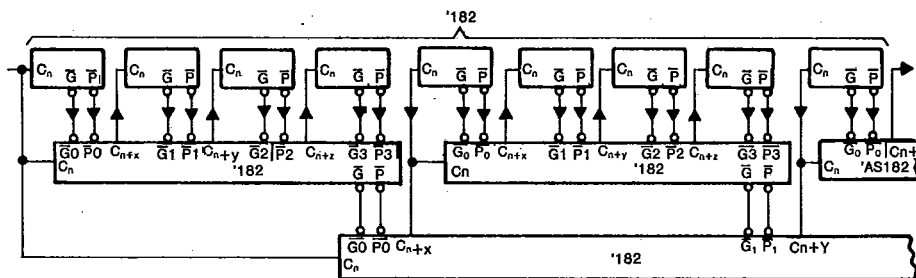
INPUTS							OUTPUT
$\bar{G}_2$	$\bar{G}_1$	$\bar{G}_0$	$\bar{P}_2$	$\bar{P}_1$	$\bar{P}_0$	$C_n$	$C_{n+z}$
L	X	X	X	X	X	X	H
X	L	X	L	X	X	X	H
X	X	L	L	L	X	X	H
X	X	X	L	L	L	H	H
All other combinations							L

H = high-level, L = low level, X = don't care  
Any inputs not shown in a given table are don't care with respect to that output.

**LOGIC DIAGRAM**



Figure; THE '182 IN A 64-BIT LOOK-AHEAD CARRY CIRCUIT



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**Absolute Maximum Ratings\***

Supply Voltage Range  $V_{CC}$  ..... -0.5V to +7V  
 DC Input Diode Current,  $I_{IK}$   
 ( $V_I < -0.5V$  or  $V_I > V_{CC} + 0.5V$ ) .....  $\pm 20$  mA  
 DC Output Diode Current,  $I_{OK}$   
 ( $V_O < -0.5V$  or  $V_O > V_{CC} + 0.5V$ ) .....  $\pm 20$  mA  
 Continuous Output Current Per Pin,  $I_O$   
 ( $-0.5V < V_O < V_{CC} + 0.5V$ ) .....  $\pm 35$  mA  
 Continuous Current Through  
 $V_{CC}$  or GND pins .....  $\pm 125$  mA  
 Storage Temperature Range,  $T_{stg}$  ... -65°C to +150°C  
 Power Dissipation Per Package,  $P_d$ † ..... 500 mW

\* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C  
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

**Recommended Operating Conditions**

Supply Voltage,  $V_{CC}$  ..... 4.5V to 5.5V  
 DC Input & Output Voltages\*,  $V_{IN}$ ,  $V_{OUT}$  ... 0V to  $V_{CC}$   
 Operating Temperature

Range KS74AHCT: -40°C to +85°C  
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times,  $t_r$ ,  $t_f$  ..... Max 500 ns

\* Unused inputs must always be tied to an appropriate logic voltage level (either  $V_{CC}$  or GND)

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}=5V \pm 10\%$  Unless Otherwise Specified)

Characteristic	Symbol	Test Conditions	$T_a = 25^\circ C$		KS74AHCT	KS54AHCT	Unit
			Typ	Guaranteed Limits		$T_a = -40^\circ C$ to $+85^\circ C$	
Minimum High-Level Input Voltage	$V_{IH}$			2.0	2.0	2.0	V
Maximum Low-Level Input Voltage	$V_{IL}$			0.8	0.8	0.8	V
Minimum High-Level Output Voltage	$V_{OH}$	$V_{IN}=V_{IH}$ or $V_{IL}$ $I_O=-20\mu A$ $I_O=-4mA$	$V_{CC}$ 4.2	$V_{CC}-0.1$ 3.98	$V_{CC}-0.1$ 3.84	$V_{CC}-0.1$ 3.7	V
Maximum Low-Level Output Voltage	$V_{OL}$	$V_{IN}=V_{IH}$ or $V_{IL}$ $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$	0	0.1 0.26 0.39	0.1 0.33 0.5	0.1 0.4	V
Maximum Input Current	$I_{IN}$	$V_{IN}=V_{CC}$ or GND		$\pm 0.1$	$\pm 1.0$	$\pm 1.0$	$\mu A$
Maximum 3-State Leakage Current	$I_{OZ}$	Output Enable = $V_{IH}$ $V_{OUT}=V_{CC}$ or GND		$\pm 0.5$	$\pm 5.0$	$\pm 10.0$	$\mu A$
Maximum Quiescent Supply Current	$I_{CC}$	$V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$		8.0	80.0	160.0	$\mu A$
Additional Worst Case Supply Current	$\Delta I_{CC}$	per input pin $V_I=2.4V$ other inputs: at $V_{CC}$ or GND $I_{OUT}=0\mu A$		2.7	2.9	3.0	mA

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**AC ELECTRICAL CHARACTERISTICS** (Input  $t_r, t_f < 2$  ns), AHCT182

Characteristic	Symbol	Conditions <sup>†</sup>	$T_a = 25^\circ\text{C}$	KS74AHCT		KS54AHCT		Unit
			$V_{CC} = 5.0\text{V}$	$T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$		$T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$		
			Typ	Min	Max	Min	Max	
Propagation Delay, $\bar{P}_i$ or $\bar{G}_i$ to $C_{n+x}, C_{n+y}, C_{n+z}$	$t_{PLH}$	$C_L = 50\text{pF}$	12		20		24	ns
	$t_{PHL}$		12		20		24	
Propagation Delay, $\bar{P}_i$ or $\bar{G}_i$ to $\bar{G}$	$t_{PLH}$	$C_L = 50\text{pF}$	12		20		24	ns
	$t_{PHL}$		12		20		24	
Propagation Delay, $C_n$ to $C_{n+x}, C_{n+y}, C_{n+z}$	$t_{PLH}$	$C_L = 50\text{pF}$	15		21		26	ns
	$t_{PHL}$		15		21		26	
Propagation Delay $\bar{P}_i$ to $\bar{P}$	$t_{PLH}$	$C_L = 50\text{pF}$	11		18		21	ns
	$t_{PHL}$		11		18		21	
Input Capacitance	$C_{IN}$		5					pF
Power Dissipation Capacitance*	$C_{PD}$							pF

\*  $C_{PD}$  determines the no-load dynamic power dissipation:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

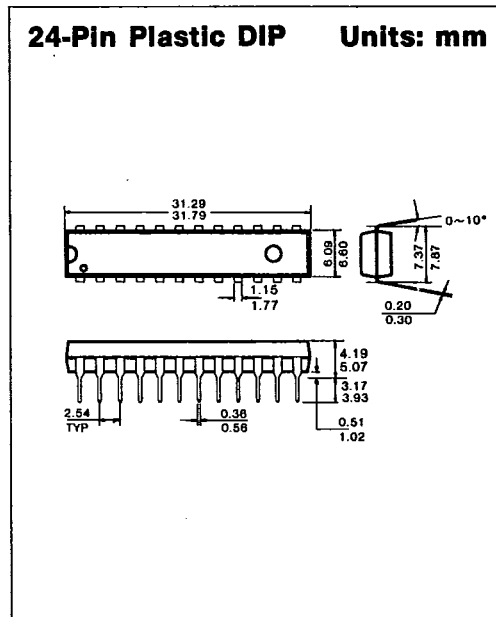
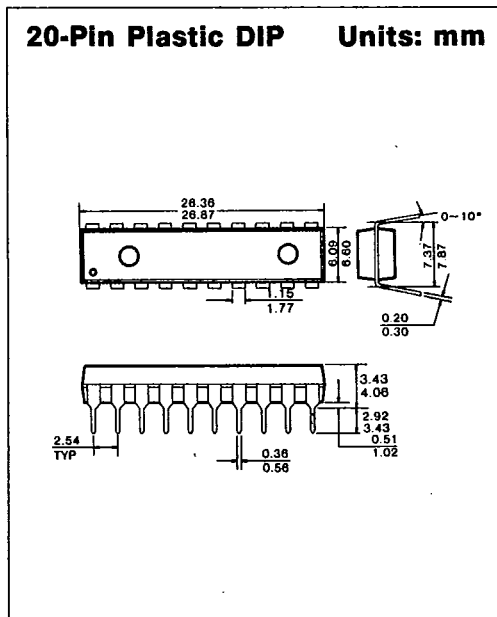
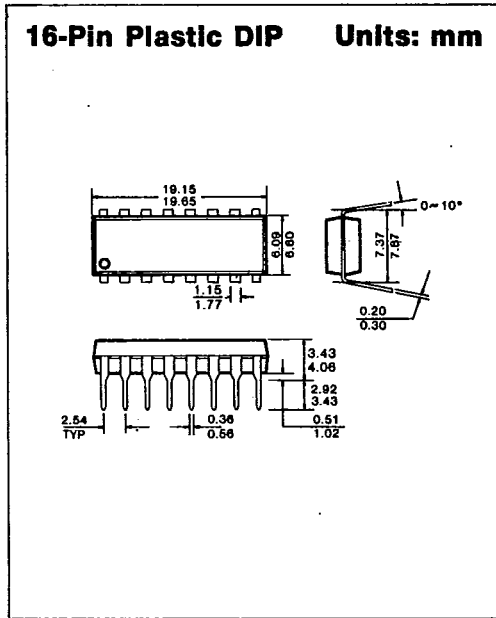
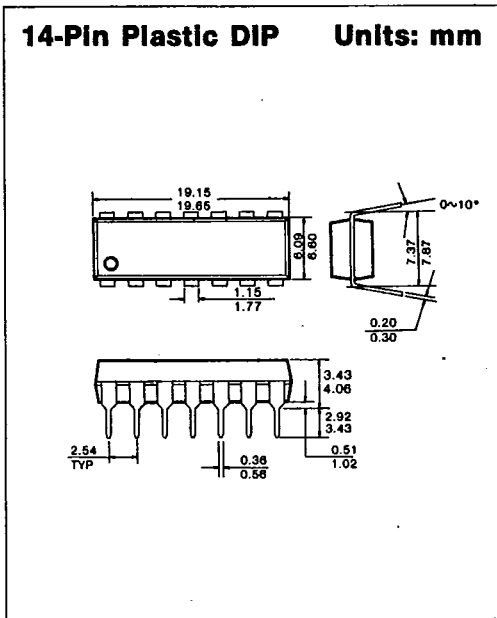
† For AC switching test circuits and timing waveforms see section 2.



**PACKAGE DIMENSIONS**

T-90-20

**1. PLASTIC PACKAGES**



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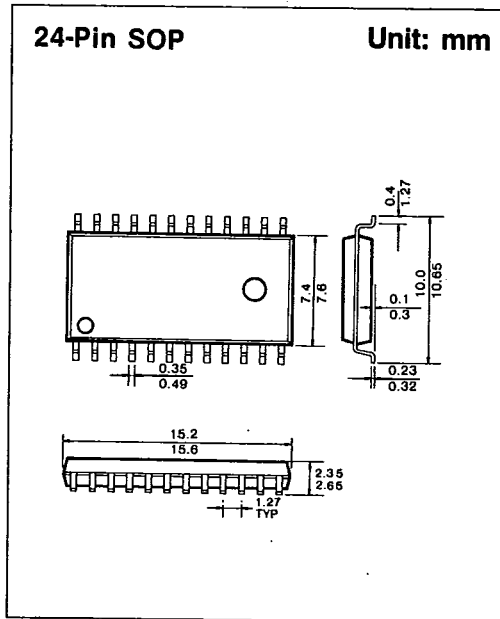
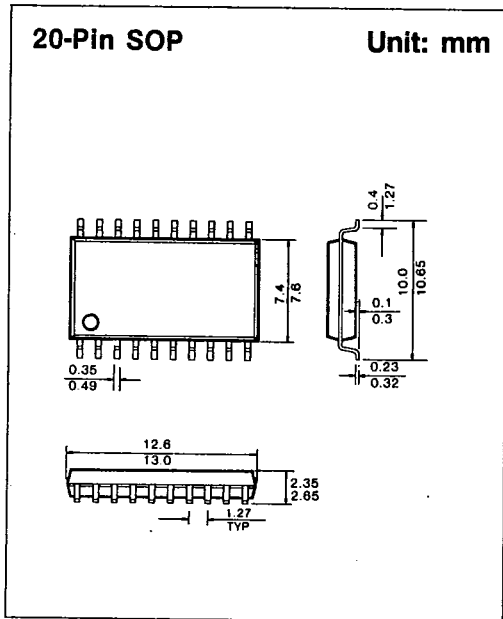
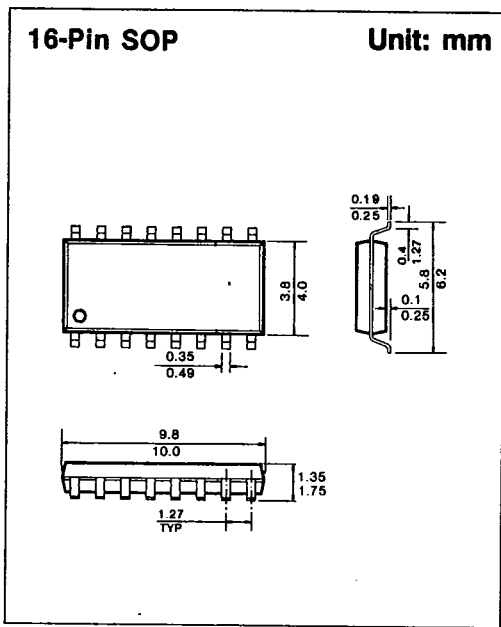
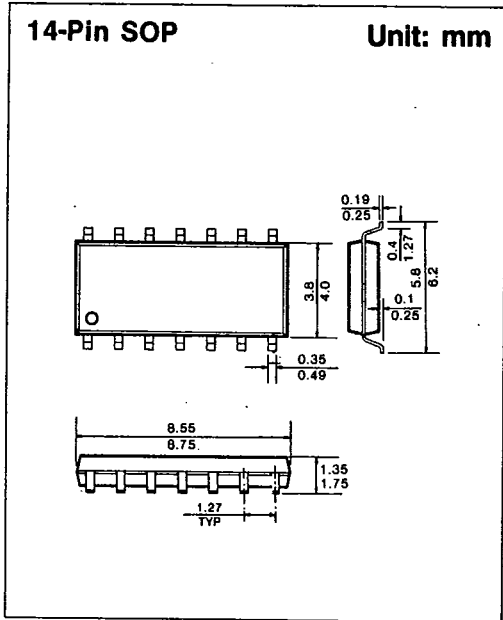
SAMSUNG SEMICONDUCTOR

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**PACKAGE DIMENSIONS**

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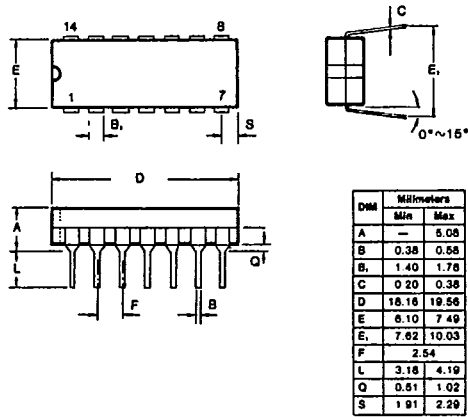


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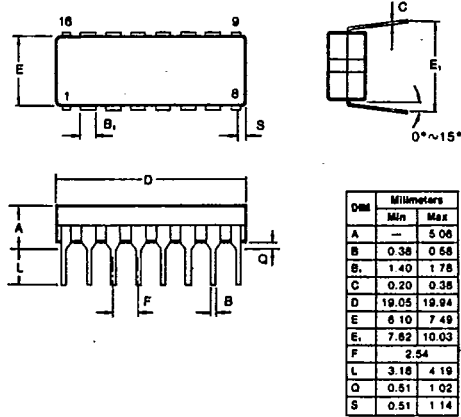
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**2. CERAMIC PACKAGES**

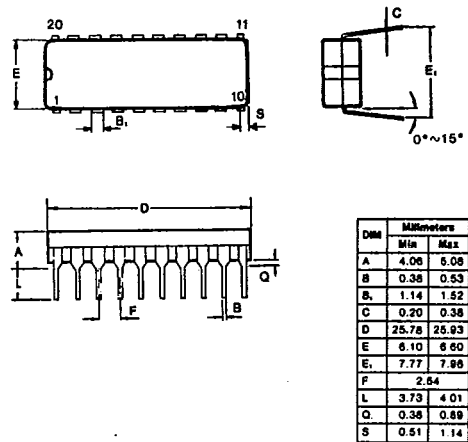
**14-Pin Ceramic DIP Units: mm**



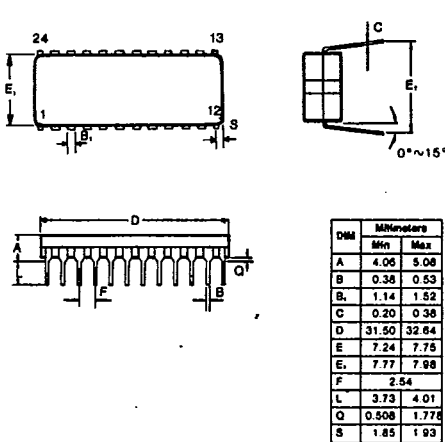
**16-Pin Ceramic DIP Units: mm**



**20-Pin Ceramic DIP Units: mm**



**24-Pin Ceramic DIP Units: mm**



7